

Ultra-linear Mixer with Integrated IF Amp and LO Buffer

Description

CMY213 is a general purpose down-converter device designed for receiver applications such as cellular and PCS mobile phones, ISM bands, GPS receivers, L-band satellite terminals, WLAN and pagers. It is particularly suited for CDMA receiver applications due to its excellent intermodulation characteristics and its high conversion gain.

The device combines an ultra-linear mixer with LO - driver and a single stage IF-amplifier in a very small SCT598 package. The mixer section of CMY213 combines low conversion losses and excellent intermodulation characteristics with low requirements of LO and DC-power. The internal level controlled LO-Buffer enables a good performance over a wide LO level range. The input and output matching of the IF amplifier can be adapted externally within a frequency range from 45 to 250 MHz.

Features

 Typical overall performance at cellular frequencies (for P_{LO} = -5dBm operation conditions: 3V, 8 mA; f_{RF} = 850 MHz;

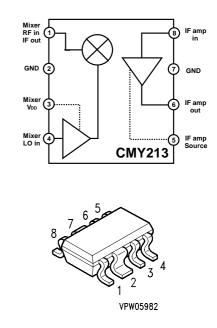
 $f_{LO} = 740 \text{ MHz}$):

- o Gain: 9.5 dB
- o Input IP3: 10 dBm
- Noise figure: 8 dB
- RF-frequency range 0.5 2.5 GHz
- Operating voltage range: 2.6 to 5V
- Small SCT598 plastic package

Applications

- Down Converter for Multiple Wireless Applications
- Cellular and PCS
 Mobile Phones
- Particularly Suited for CDMA Receivers
- ISM and WLAN Receivers
- GPS Receivers

Package Outline and Pin Configuration, SCT598



Maximum Ratings

Parameter	Port	Symbol	Value		Unit
			min	max	
Supply Voltage	3,6	V_{DD}	0	5	V
DC-Voltage at LO Input	4	V_6	-3	0,5	V
DC-Voltage at Mixer RF-IF Port	1	V ₈	- 0,5	+ 0,5	V
Power into Mixer RF Port	1	P_{RF}		10	dBm
Power into LO Input	4	$P_{in,LO}$	-10	10	dBm
Channel Temperature		T_{Ch}		150	Ĉ
Operating Temperature		T _{op}	-30	85	Ĉ
Storage Temperature		T _{stg}	-55	150	C
Thermal Resistance*					
Channel to Soldering Point (Gl	ND)	R_{thChS}	20	60	K/W

Electrical Characteristics

Parameter,	Comment	min	typ	max	Unit
RF - frequency range	external match	0.5	-	2.5	GHz
LO - Frequency range	external match	0.5	-	2.5	GHz
IF Frequency range	external match	45		250	MHz

Typical performance at cellular frequencies*:

 $T_a = 25$ °C; $V_{DD} = 3$ V, $f_{RF} = 850$ MHz; $f_{LO} = 740$ MHz; $P_{LO} = -5$ dBm; $f_{IF} = 110$ MHz, $Z_s = Z_L = 50$ Ohm; unless otherwise specified

Parameter, Test Conditions	Symbol	min	typ	max	Unit
Total operating Current (Mixer + IF amplifier)	I _{op}	-	8.0	9.5	mA
Conversion Gain	G _c	8.0	9.5	-	dB
SSB Noise Figure	F _{ssb}	-	8	-	dB
RF Input -/ IF Output return loss (external matching required)	RFIrl / IFOrl	-	10	-	dB
3rd Order Input Intercept Point	IIP3	8	10	-	dBm
LO-RF Isolation	lso	-	10	-	DB

Test conditions at PCS frequencies:

 $T_a = 25$ °C; $V_{DD} = 3$ V, $f_{RF} = 1960$ MHz; $f_{LO} = 1750$ MHz; $P_{LO} = -5$ dBm; $f_{IF} = 210$ MHz, $Z_s = Z_L = 50$ Ohm; unless otherwise specified

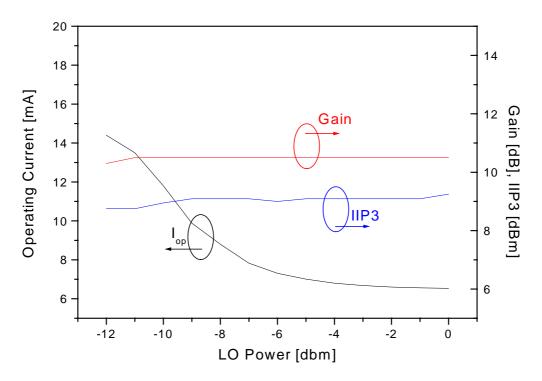
Parameter, Test Conditions	Symbol	min	typ	max	Unit
Total operating Current (Mixer + IF amplifier)	I _{op}	-	8.0	9.5	mA
Conversion Gain	G _c	7	8.5	-	dB
SSB Noise Figure	F _{ssb}	-	8.5	-	dB
RF Input -/ IF output return loss (external matching required)	RFIrl / IFOrl	-	10	-	dB
3rd Order Input Intercept Point	IIP3	10	12	-	dBm
LO-RF Isolation	lso	-	6	-	dB

* IMPORTANT NOTE:

During production, the RF performance at PCS frequencies is screened. The passed devices also achieve the specified RF performance at cellular frequencies.

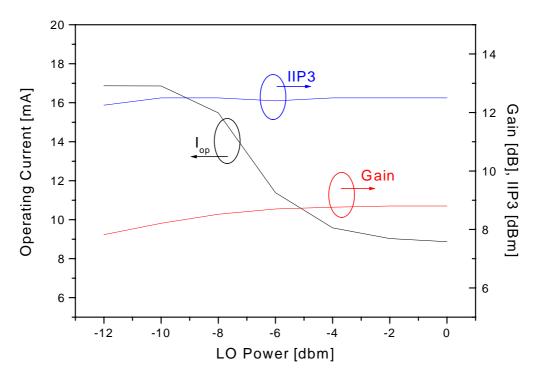
Typical device behavior at cellular frequencies:

 $T_a = 25$ °C; $V_{DD} = 3$ V, $f_{RF} = 850$ MHz; $f_{LO} = 740$ MHz; $f_{IF} = 110$ MHz, $Z_s = Z_L = 50$ Ohm; unless otherwise specified



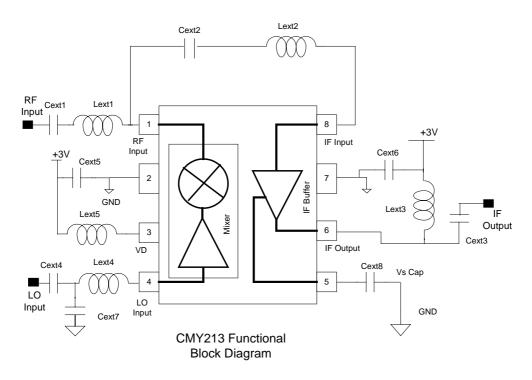
Typical device behavior at PCS frequencies:

 $T_a = 25$ °C; $V_{DD}= 3V$, $f_{RF} = 1960$ MHz; $f_{LO} = 1750$ MHz; $f_{IF} = 210$ MHz, $Z_s = Z_L = 50$ Ohm; unless otherwise specified



For additional information and latest specifications, see our website: <u>www.triquint.com</u> Revision C, September 12, 2006

Applications Information Test circuit / application example



External components for cellular frequencies

 $f_{\rm RF} = 850 \text{MHz}; f_{\rm LO} = 740 \text{MHz}; f_{\rm IF} = 110 \text{MHz}$

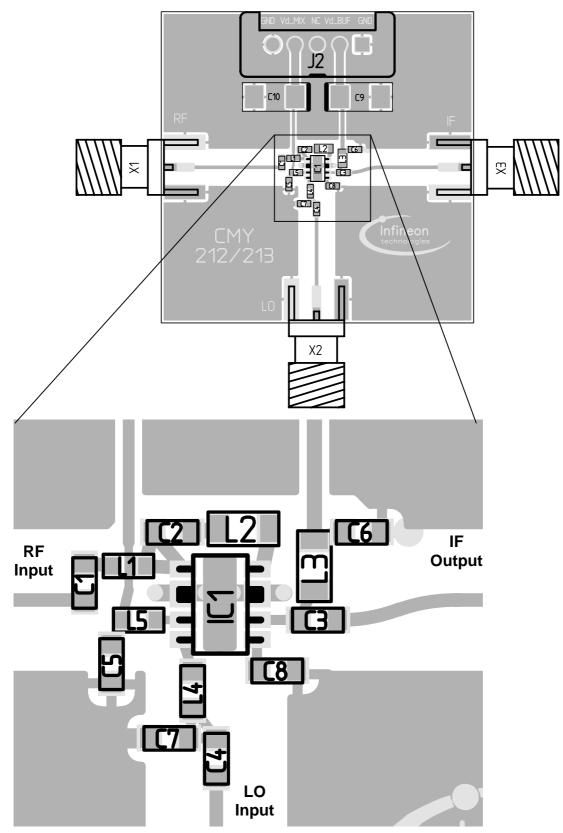
Capacitors	(Murata 0402)	Inductors	(Toko)
Cext1	1.5 pF	Lext1	27 nH <i>LL1005</i>
Cext2	1 nF	Lext2	180 nH <i>LL160</i> 8
Cext3	18 pF	Lext3	150 nH <i>LL160</i> 8
Cext4	100 pF	Lext4	27 nH <i>LL1005</i>
Cext5	1 nF	Lext5	27 nH <i>LL1005</i>
Cext6	1 nF		
Cext7	3 pF		
Cext8	100 nF		

External components for PCS frequencies

 $f_{\rm RF} = 1960 \text{MHz}; f_{\rm LO} = 1750 \text{MHz}; f_{\rm IF} = 210 \text{MHz}$

Capacitors	(Murata 0402)	Inductors	(Toko)
Cext1	1 pF	Lext1	5.6 nH <i>LL1005</i>
Cext2	1 nF	Lext2	68 nH <i>LL1608</i>
Cext3	8 pF	Lext3	68 nH <i>LL1608</i>
Cext4	22 pF	Lext4	4.7 nH <i>LL1005</i>
Cext5	1 nF	Lext5	4.7 nH <i>LL1005</i>
Cext6	1 nF		
Cext7	3 pF		
Cext8	100 nF		

Applications Information (cont) PCB-Layout Size: 35 x 35 mm²

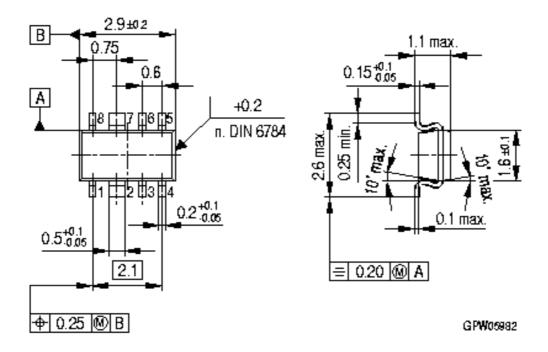


General description and notes

CMY213 is a general purpose down-converter device designed for multiple applications such as cellular and PCS mobile phones, ISM bands, GPS receivers, L-band satellite terminals, WLAN and pagers. Due to its excellent intermodulation characteristics and its high conversion gain, CMY213 is particularly suited for CDMA receiver applications.

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Ordering Information

Туре	Marking	Ordering code (tape and reel)	Package ¹⁾
CMY213	213	CMY213	SCT598-8-1

Additional Information

This part is compliant with RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment).

The part is rated Moisture Sensitivity Level 1 at 260℃ per JEDEC standard IPC/JEDEC J-STD-020.

ESD: Electrostatic discharge sensitive device. Observe handling Precautions.

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